DATA SHEET

NEC

DARLINGTON POWER TRANSISTOR

2SC4811

NPN SILICON EPITAXIAL TRANSISTOR (DARLINGTON CONNECTION) FOR HIGH-SPEED SWITCHING

The 2SC4811 is a high-speed Darlington power transistor. This transistor is ideal for high-precision control such as PWM control for pulse motors or brushless motors in OA and FA equipment.

In addition, this transistor features a package that can be auto-mounted in radial taping specifications, thus contributing to mounting cost reduction.

FEATURES

- Auto-mounting possible in radial taping specifications
- Resin-molded insulation type package with power rating of 1.8 W in stand-alone conditions
- On-chip C-to-E reverse diode
- Fast switching speed

ABSOLUTE MAXIMUM RATINGS (Ta = 25°C)

Parameter	Symbol	Ratings	Unit
Collector to base voltage	V_{CBO}	100	V
Collector to emitter voltage	V_{CEO}	100	V
Emitter to base voltage	V_{EBO}	8.0	V
Collector current (DC)	$I_{C(DC)}$	±8.0	A
Collector current (pulse)	$I_{C(pulse)}$*	±16	A
Base current (DC)	$I_{B(DC)}$	0.8	A
Total power dissipation	P_T**	1.8	W
Junction temperature	T_j	150	°C
Storage temperature	T_{stg}	−55 to +150	°C

* PW ≤ 300 μs, duty cycle ≤ 10%

** T_a = 25°C

勝 特 力 材 料 886-3-5753170
胜特力电子(上海) 86-21-54151736
胜特力电子(深圳) 86-755-83298787
Http://www.100y.com.tw

The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version.
Not all devices/types available in every country. Please check with local NEC representative for availability and additional information.

Document No. D15602EJ2V0DS00 (2nd edition)
Date Published April 2002 N CP(K)
Printed in Japan

© NEC Corporation 2002

ELECTRICAL CHARACTERISTICS (Ta = 25°C)

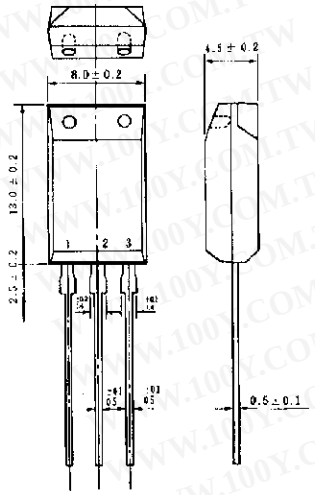
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector cutoff current	I_{CBO}	V_{CB} = 100 V, I_E = 0			1.0	μA
Emitter cutoff current	I_{EBO}	V_{EB} = 5 V, I_C = 0			5.0	mA
DC current gain	h_{FE1}*	V_{CE} = 2.0 V, I_C = 4.0 A	2,000		20,000	
DC current gain	h_{FE2}*	V_{CE} = 2.0 V, I_C = 8.0 A	500			
Collector saturation voltage	$V_{CE(sat)}$*	I_C = 4.0 A, I_B = 4.0 mA			1.5	V
Base saturation voltage	$V_{BE(sat)}$*	I_C = 4.0 A, I_B = 4.0 mA			2.0	V
Turn-on time	t_{on}	I_C = 4.0 A, I_{B1} = $-I_{B2}$ = 4.0 mA R_L = 12.5 Ω, V_{CC} ≅ 50 V Refer to the test circuit.		0.5		μs
Storage time	t_{stg}			2.5		μs
Fall time	t_f			0.6		μs
Collector capacitance	C_{ob}	V_{CB} = 10 V, I_E = 0 , f = 1 MHz		45		pF

* Pulse test PW ≤ 350 μs, duty cycle ≤ 2%

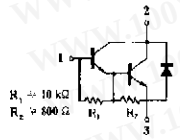
h_{FE} CLASSIFICATION

Marking	M	L	K
h_{FE1}	2,000 to 5,000	4,000 to 10,000	8,000 to 20,000

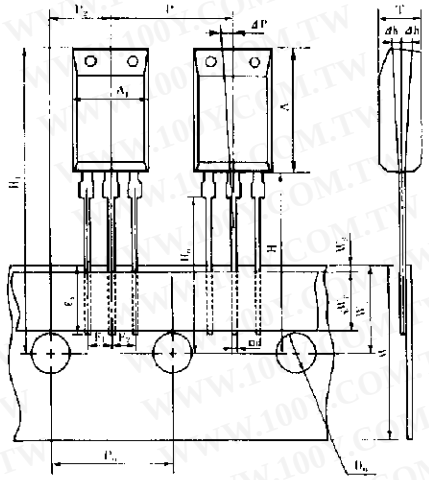
PACKAGE DRAWING (UNIT: mm)



Electrode Connection
1. Base
2. Collector
3. Emitter



TAPING SPECIFICATION



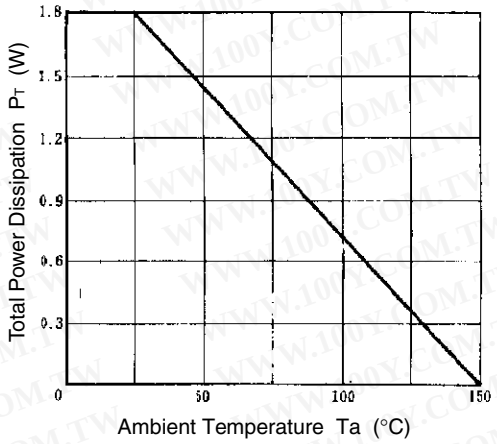
A_1	8.0 ± 0.2
A	13.0 ± 0.2
D_0	φ4.0 ± 0.2
d	0.5 ± 0.1
F_1	$2.5^{+0.4}_{-0.1}$
F_2	$2.5^{-0.4}_{-0.1}$
H	20.0 MAX.
H_0	16.0 ± 0.5
H_1	32.2 MAX.
Δh	0 + 1.0
ℓ_1	2.5 MIN.
P	12.7 ± 1.0
P_0	12.7 ± 0.3
P_2	6.35 ± 0.5
ΔP	0 ± 1.3
T	4.5 + 0.2
W	$18.0^{+1.0}_{-0.5}$
W_0	5.0 MIN.
W_1	9.0 ± 0.5
W_2	0.7 MIN.

勝 特 力 材 料 886-3-5753170
胜特力电子(上海) 86-21-54151736
胜特力电子(深圳) 86-755-83298787
Http://www.100y.com.tw

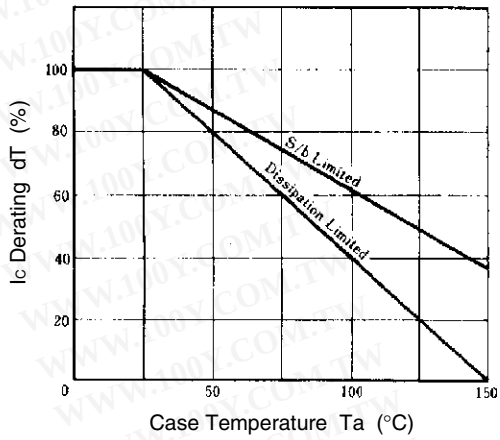
勝 特 力 材 料 886-3-5753170
胜特力电子(上海) 86-21-54151736
胜特力电子(深圳) 86-755-83298787
Http://www.100y.com.tw

TYPICAL CHARACTERISTICS (Ta = 25°C)

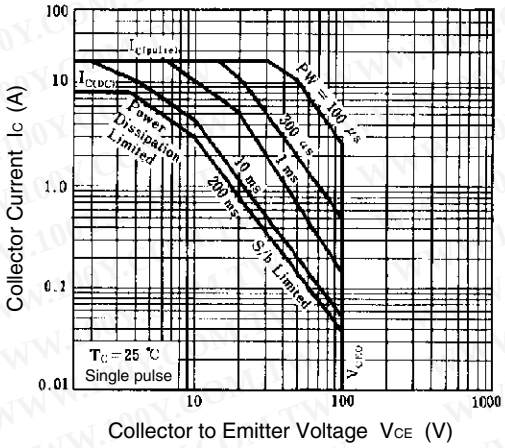
TOTAL POWER DISSIPATION vs. AMBIENT TEMPERATURE



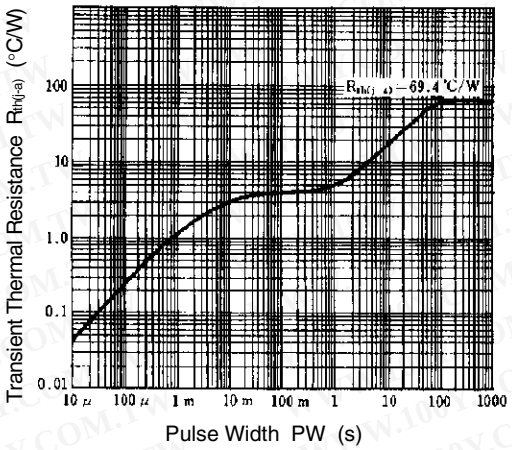
DERATING CURVE OF SAFE OPERATING AREA



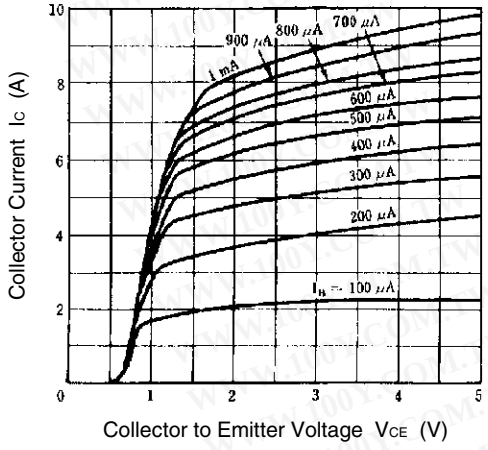
FORWARD BIAS SAFE OPERATING AREA



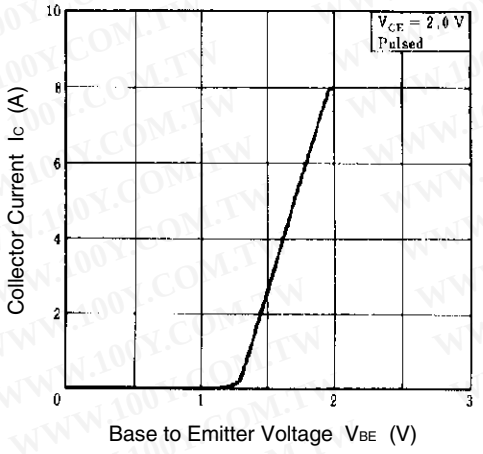
TRANSIENT THRMAL RESISTANCE



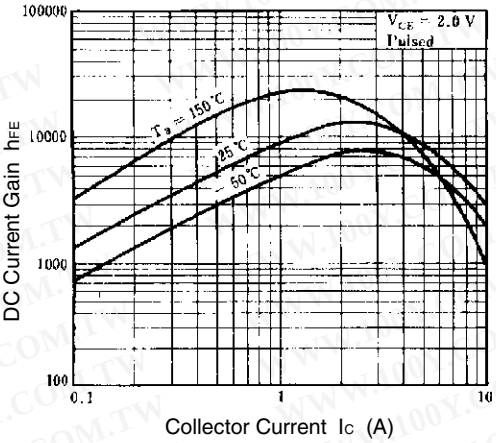
COLLECTOR CURRENT vs. COLLECTOR TO EMITTER VOLTAGE



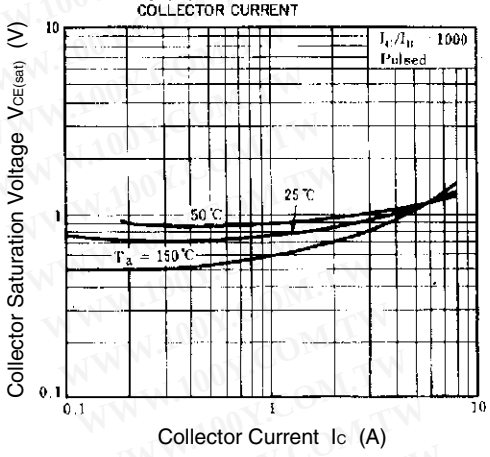
COLLECTOR CURRENT vs. BASE TO EMITTER VOLTAGE



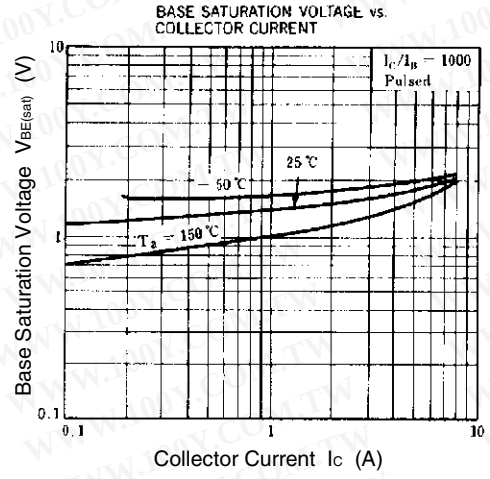
DC CURRENT GAIN vs. COLLECTOR CURRENT



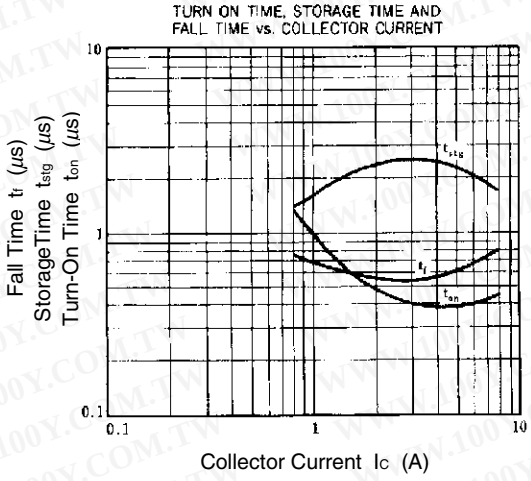
COLLECTOR SATURATION VOLTAGE vs. COLLECTOR CURRENT



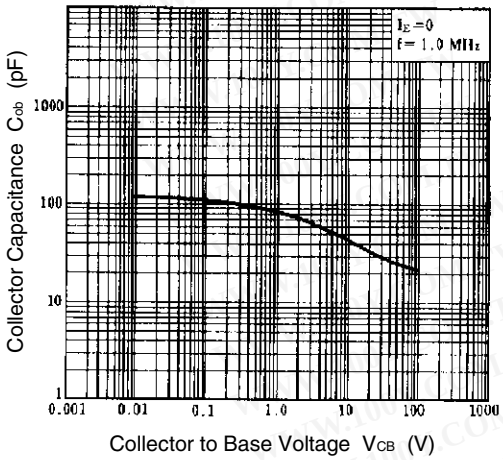
BASE SATURATION VOLTAGE vs. COLLECTOR CURRENT



TURN ON TIME, STORAGE TIME AND FALL TIME vs. COLLECTOR CURRENT

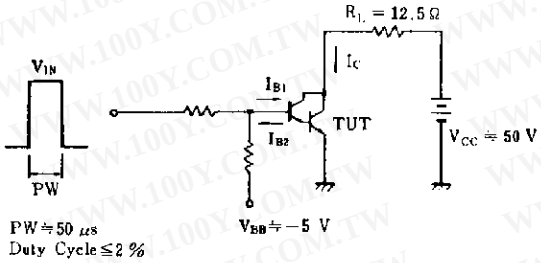


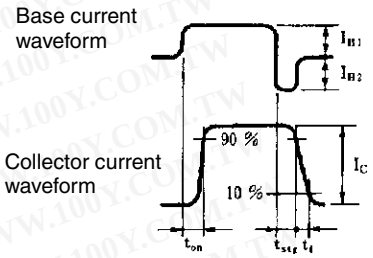
OUTPUT CAPACITANCE vs. COLLECTOR TO BASE VOLTAGE



勝 特 力 材 料 886-3-5753170
胜特力电子(上海) 86-21-54151736
胜特力电子(深圳) 86-755-83298787
Http://www.100y.com.tw

SWITCHING TIME (t_{on}, t_{stg}, t_f) TEST CIRCUIT





勝 特 力 材 料 886-3-5753170
胜特力电子(上海) 86-21-54151736
胜特力电子(深圳) 86-755-83298787
Http://www.100y.com.tw

勝 特 力 材 料 886-3-5753170
胜特力电子(上海) 86-21-54151736
胜特力电子(深圳) 86-755-83298787
Http://www.100y.com.tw

- **The information in this document is current as of July, 2001. The information is subject to change without notice. For actual design-in, refer to the latest publications of NEC's data sheets or data books, etc., for the most up-to-date specifications of NEC semiconductor products. Not all products and/or types are available in every country. Please check with an NEC sales representative for availability and additional information.**
- No part of this document may be copied or reproduced in any form or by any means without prior written consent of NEC. NEC assumes no responsibility for any errors that may appear in this document.
- NEC does not assume any liability for infringement of patents, copyrights or other intellectual property rights of third parties by or arising from the use of NEC semiconductor products listed in this document or any other liability arising from the use of such products. No license, express, implied or otherwise, is granted under any patents, copyrights or other intellectual property rights of NEC or others.
- Descriptions of circuits, software and other related information in this document are provided for illustrative purposes in semiconductor product operation and application examples. The incorporation of these circuits, software and information in the design of customer's equipment shall be done under the full responsibility of customer. NEC assumes no responsibility for any losses incurred by customers or third parties arising from the use of these circuits, software and information.
- While NEC endeavours to enhance the quality, reliability and safety of NEC semiconductor products, customers agree and acknowledge that the possibility of defects thereof cannot be eliminated entirely. To minimize risks of damage to property or injury (including death) to persons arising from defects in NEC semiconductor products, customers must incorporate sufficient safety measures in their design, such as redundancy, fire-containment, and anti-failure features.
- NEC semiconductor products are classified into the following three quality grades:
  "Standard", "Special" and "Specific". The "Specific" quality grade applies only to semiconductor products developed based on a customer-designated "quality assurance program" for a specific application. The recommended applications of a semiconductor product depend on its quality grade, as indicated below. Customers must check the quality grade of each semiconductor product before using it in a particular application.
  "Standard": Computers, office equipment, communications equipment, test and measurement equipment, audio and visual equipment, home electronic appliances, machine tools, personal electronic equipment and industrial robots
  "Special": Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support)
  "Specific": Aircraft, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems and medical equipment for life support, etc.
  The quality grade of NEC semiconductor products is "Standard" unless otherwise expressly specified in NEC's data sheets or data books, etc. If customers wish to use NEC semiconductor products in applications not intended by NEC, they must contact an NEC sales representative in advance to determine NEC's willingness to support a given application.
  (Note)
  (1) "NEC" as used in this statement means NEC Corporation and also includes its majority-owned subsidiaries.
  (2) "NEC semiconductor products" means any semiconductor product developed or manufactured by or for NEC (as defined above).

M8E 00.4